## NSN 5961-01-232-7675

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-232-7675 **Inclosure Material:** Plastic or ceramic **Overall Length:** 0.808 inches **Overall Height:** 0.308 inches **Overall Width:** 0.320 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source all transistor and 40.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor **Current Rating Per Characteristic:** 400.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 2.0 watts total power dissipation all transistor **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0